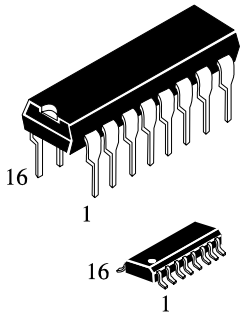
IW4042B

Quad Clocked «D» Latch
High-Voltage Silicon-Gate CMOS

IW4042B types contain four latch circuits, each strobed by a common clock. Complementary buffered outputs are available from each circuit. The impedance of the n- and p-channel output devices is balanced and all outputs are electrically identical. Information present at the data input is transferred to outputs Q and $\overline{Q}$ during the CLOCK level which is programmed by the POLARITY input. For POLARITY = 0 the transfer occurs during the 0 CLOCK level and for POLARITY = 1 the transfer occurs during the 1 CLOCK level. The outputs follow the data input providing the CLOCK and POLARITY levels defined above are present. When a CLOCK transition occurs (positive for POLARITY = 0 and negative for POLARTY = 1) the information present at the input during the CLOCK transition is retained at the outputs until an opposite CLOCK transition occurs.

The IW4042B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes); 16-lead dual-in-line plastic package (E suffix), and in chip form (H suffix).

- Operating Voltage Range: 3.0 to 18 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):
  1.0 V min @ 5.0 V supply
  2.0 V min @ 10.0 V supply
  2.5 V min @ 15.0 V supply

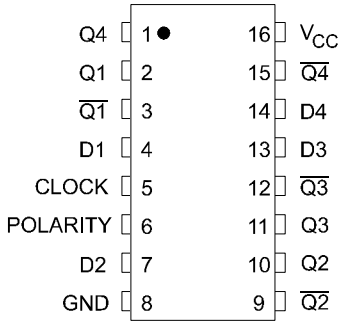


N SUFFIX
PLASTIC

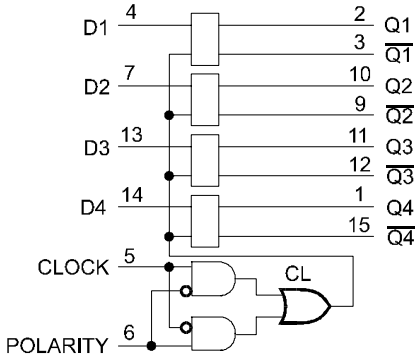
D SUFFIX
SOIC

ORDERING INFORMATION
IW4042BN Plastic
IW4042BD SOIC
T_A = -55° to 125° C for all packages

PIN ASSIGNMENT



LOGIC DIAGRAM



PIN 16 =V_{CC}
PIN 8 = GND

FUNCTION TABLE

Inputs		Outputs
Clock	Polarity	Q
0	0	D
1	0	Latch
1	1	D
0	1	Latch

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +20	V
V_I	DC Input Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
V_{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
I_I	DC Input Current, per Pin	±10	mA
P_D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Ptot	Power Dissipation per Output Transistor	100	mW
Tstg	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.
+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package: : - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	3.0	18	V
V_I, V_{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V_{CC}	V
T_A	Operating Temperature, All Package Types	-55	+125	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND≤(V_{IN} or V_{OUT})≤V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				≥-55°C	25°C	≤125 °C	
V_{IH}	Minimum High-Level Input Voltage	V_{OUT}=0.5 V or V_{CC} - 0.5 V V_{OUT}=1.0 V or V_{CC} - 1.0 V V_{OUT}=1.5 V or V_{CC} - 1.5 V	5.0 10 15	3.5 7 11	3.5 7 11	3.5 7 11	V
V_{IL}	Maximum Low - Level Input Voltage	V_{OUT}=0.5 V or V_{CC} - 0.5 V V_{OUT}=1.0 V or V_{CC} - 1.0 V V_{OUT}=1.5 V or V_{CC} - 1.5 V	5.0 10 15	1.5 3 4	1.5 3 4	1.5 3 4	V
V_{OH}	Minimum High-Level Output Voltage	V_{IN}=GND or V_{CC}	5.0 10 15	4.95 9.95 14.95	4.95 9.95 14.95	4.95 9.95 14.95	V
V_{OL}	Maximum Low-Level Output Voltage	V_{IN}=GND or V_{CC}	5.0 10 15	0.05 0.05 0.05	0.05 0.05 0.05	0.05 0.05 0.05	V
I_{IN}	Maximum Input Leakage Current	V_{IN}= GND or V_{CC}	18	±0.1	±0.1	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	V_{IN}= GND or V_{CC}	5.0 10 15 20	1 2 4 20	1 2 4 20	30 60 120 600	μA
I_{OL}	Minimum Output Low (Sink) Current	V_{IN}= GND or V_{CC} V_{OL}=0.4 V V_{OL}=0.5 V V_{OL}=1.5 V	 5.0 10 15	 0.64 1.6 4.2	 0.51 1.3 3.4	 0.36 0.9 2.4	mA
I_{OH}	Minimum Output High (Source) Current	V_{IN}= GND or V_{CC} V_{OH}=2.5 V V_{OH}=4.6 V V_{OH}=9.5 V V_{OH}=13.5 V	 5.0 5.0 10 15	 -2.0 -0.64 -1.6 -4.2	 -1.6 -0.51 -1.3 -3.4	 -1.15 -0.36 -0.9 -2.4	mA

AC ELECTRICAL CHARACTERISTICS (C_L=50pF, R_L=200 kΩ, Input t_r=t_f=20 ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit ≥-55°C	Guaranteed Limit 25°C	Guaranteed Limit ≤125°C	Unit
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Clock to Q (Figure 1)	5.0 10 15	450 200 160	450 200 160	900 400 320	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Clock to $\overline{Q}$ (Figure 1)	5.0 10 15	500 230 180	500 230 180	1000 460 360	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Data to Q (Figure 2)	5.0 10 15	220 110 80	220 110 80	440 220 160	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Data to $\overline{Q}$ (Figure 2)	5.0 10 15	300 150 100	300 150 100	600 300 200	ns
t_{TLH}, t_{THL}	Maximum Output Transition Time, Any Output (Figure 1)	5.0 10 15	200 100 80	200 100 80	400 200 160	ns
C_{IN}	Maximum Input Capacitance	-		7.5		pF

TIMING REQUIREMENTS (C_L=50pF, R_L=200 kΩ, Input t_r=t_f=20 ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit ≥-55°C	Guaranteed Limit 25°C	Guaranteed Limit ≤125°C	Unit
t_w	Minimum Pulse Width, Clock (Figure 1)	5.0 10 15	200 100 60	200 100 60	400 200 120	ns
t_{su}	Minimum Setup Time, Data to Clock (Figure 1)	5.0 10 15	50 30 25	50 30 25	100 60 50	ns
t_h	Minimum Hold Time, Clock to Data (Figure 1)	5.0 10 15	120 60 50	120 60 50	240 120 100	ns
t_r, t_f	Maximum Input Rise or Fall Time, Clock (Figure 1)	5.0 10 15	Not rise or fall time sensitive			μs

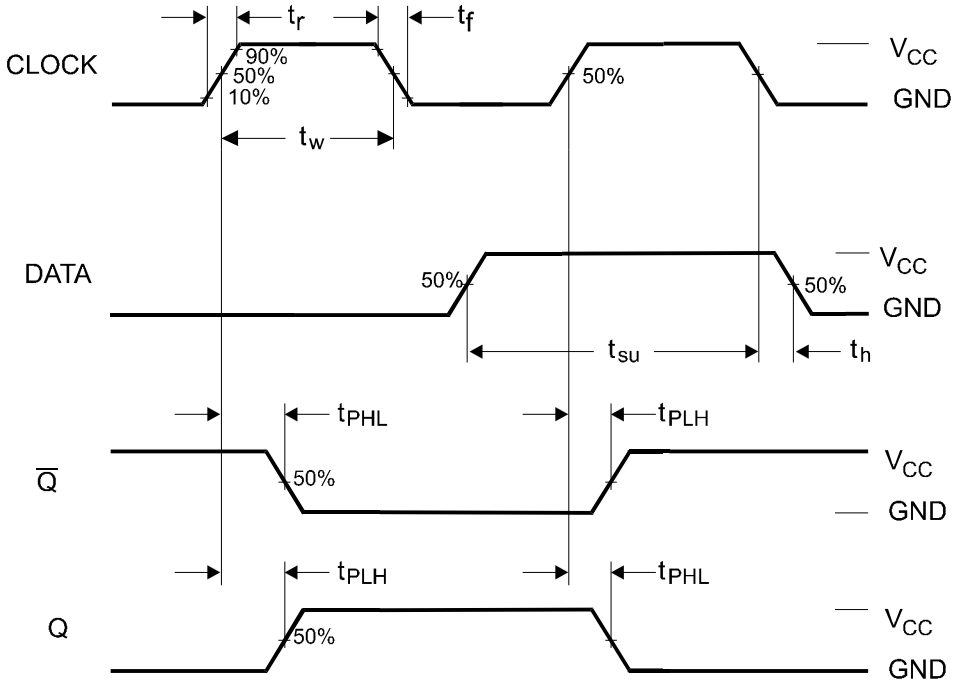


Figure 1. Switching Waveforms

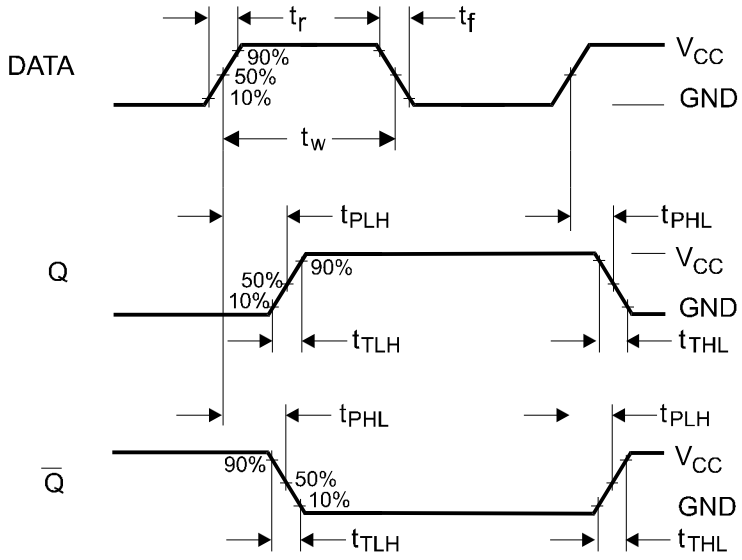
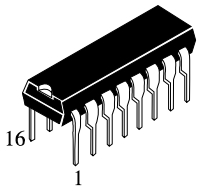
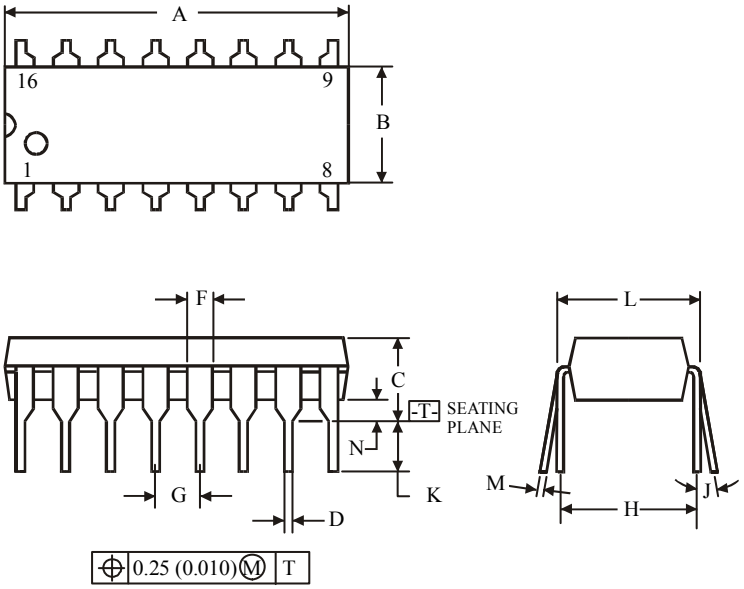


Figure 2. Switching Waveforms

N SUFFIX PLASTIC
(MS - 001BB)



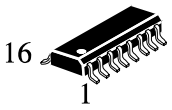


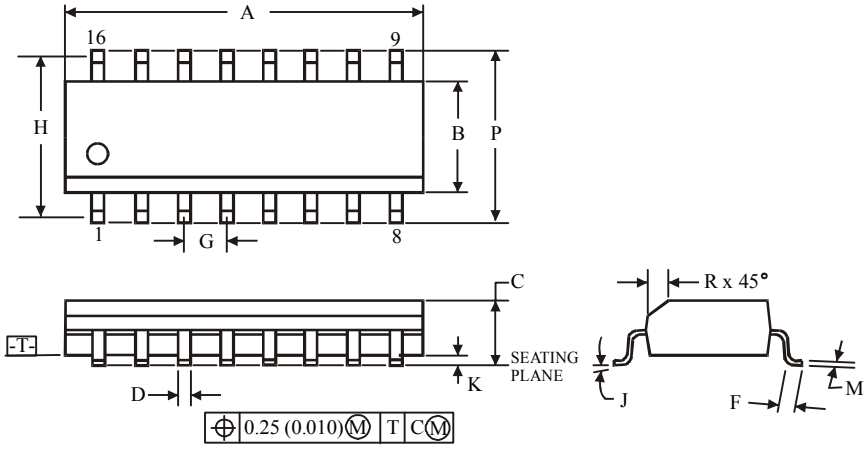
Symbol	Dimensions, mm	
	MIN	MAX
A	18.67	19.69
B	6.10	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.20	0.36
N	0.38	

NOTES:

1. imensions “A”, “B” do not include mold flash or protrusions. Maximum mold flash or protrusions 0.25 mm (0.010) per side.

D SUFFIX SOIC
(MS - 012AC)





Symbol.	Dimensions, mm	
	MIN	MAX
A	9.80	10.0
B	3.80	4.00
C	1.35	1.75
D	0.33	0.51
F	0.40	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.10	0.25
M	0.19	0.25
P	5.80	6.20
R	0.25	0.50

NOTES:

1.Dimensions A and B do not include mold flash or protrusion.
2.Maximum mold flash or protrusion 0.15 mm (0.006) per side for A, for B - 0.25 mm (0.010) per side.

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

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